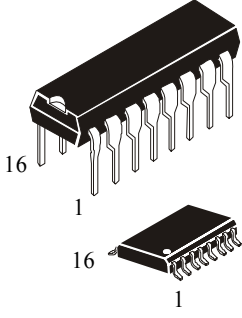


**IW4040B**

**12-Stage Binary Ripple Counter**  
**High-Voltage Silicon-Gate CMOS**

The IW4040B is ripple-carry binary counter. All counter stages are master-slave flip-flops. The state of a counter advances one count on the negative transition of each input pulse; a high level on the RESET line resets the counter to its all zeros state. Schmitt trigger action on the input-pulse line permits unlimited rise and fall times.

- Operating Voltage Range: 3.0 to 18 V
- Maximum input current of 1  $\mu$ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):
  - 1.0 V min @ 5.0 V supply
  - 2.0 V min @ 10.0 V supply
  - 2.5 V min @ 15.0 V supply



N SUFFIX  
PLASTIC DIP

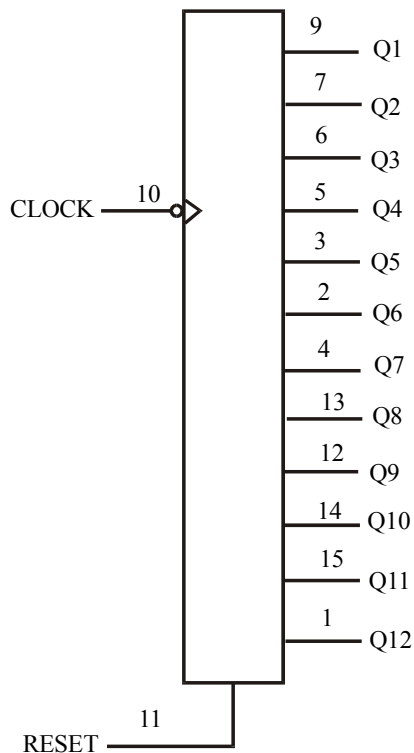
D SUFFIX  
SOIC

**ORDERING INFORMATION**

**IW4040BN** Plastic DIP  
**IW4040BD** SOIC

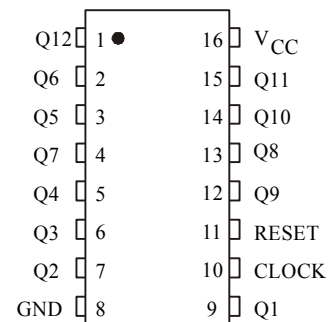
T<sub>A</sub> = -55° to 125° C for all packages

**LOGIC DIAGRAM**





PIN 16 = V<sub>CC</sub>  
 PIN 8 = GND

**PIN ASSIGNMENT**



**FUNCTION TABLE**

Inputs		Output
Clock	Reset	Output state
	L	No change
	L	Advance to next state
X	H	All Outputs are low

H= high level  
 L = low level  
 X=don't care

**MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +20	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±10	mA
P <sub>D</sub>	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	500* <sup>1</sup>	mW
P <sub>tot</sub>	Power Dissipation per Output Transistor	100	mW
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

\*Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

\*<sup>1</sup> For T<sub>A</sub>=-55 to 100°C (package plastic DIP), for T<sub>A</sub>=-55 to 65°C (package SOIC)

+Derating - Plastic DIP: - 12 mW/°C from 100°C to 125°C  
SOIC Package: - 7 mW/°C from 65°C to 125°C

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	3.0	18	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types	-55	+125	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>IN</sub> and V<sub>OUT</sub> should be constrained to the range GND ≤ (V<sub>IN</sub> or V<sub>OUT</sub>) ≤ V<sub>CC</sub>.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

**DC ELECTRICAL CHARACTERISTICS** (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	Guaranteed Limit			Unit
				-55°C	25°C	125°C	
V <sub>IH</sub>	Minimum High-Level Input Voltage	V <sub>OUT</sub> =0.5 V or V <sub>CC</sub> - 0.5 V V <sub>OUT</sub> =1.0 V or V <sub>CC</sub> - 1.0 V V <sub>OUT</sub> =1.5 V or V <sub>CC</sub> - 1.5 V	5.0	3.5	3.5	3.5	V
			10	7.0	7.0	7.0	
			15	11.0	11.0	11.0	
V <sub>IL</sub>	Maximum Low -Level Input Voltage	V <sub>OUT</sub> =0.5 V or V <sub>CC</sub> - 0.5 V V <sub>OUT</sub> =1.0 V or V <sub>CC</sub> - 1.0 V V <sub>OUT</sub> =1.5 V or V <sub>CC</sub> - 1.5 V	5.0	1.5	1.5	1.5	V
			10	3.0	3.0	3.0	
			15	4.0	4.0	4.0	
V <sub>OH</sub>	Minimum High-Level Output Voltage	V <sub>IN</sub> = GND or V <sub>CC</sub>	5.0	4.95	4.95	4.95	V
			10	9.95	9.95	9.95	
			15	14.95	14.95	14.95	
V <sub>OL</sub>	Maximum Low-Level Output Voltage	V <sub>IN</sub> = GND or V <sub>CC</sub>	5.0	0.05	0.05	0.05	V
			10	0.05	0.05	0.05	
			15	0.05	0.05	0.05	
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> = GND or V <sub>CC</sub>	18	±0.1	±0.1	±1.0	µA
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	V <sub>IN</sub> = GND or V <sub>CC</sub>	5.0	5	5	150	µA
			10	10	10	300	
			15	20	20	600	
			20	100	100	3000	
I <sub>OL</sub>	Minimum Output Low (Sink) Current	V <sub>IN</sub> = GND or V <sub>CC</sub> U <sub>OL</sub> =0.4 V U <sub>OL</sub> =0.5 V U <sub>OL</sub> =1.5 V	5.0	0.64	0.51	0.36	mA
			10	1.6	1.3	0.9	
			15	4.2	3.4	2.4	
I <sub>OH</sub>	Minimum Output High (Source) Current	V <sub>IN</sub> = GND or V <sub>CC</sub> U <sub>OH</sub> =2.5 V U <sub>OH</sub> =4.6 V U <sub>OH</sub> =9.5 V U <sub>OH</sub> =13.5 V	5.0	-2.0	-1.6	-1.15	mA
			5.0	-0.64	-0.51	-0.36	
			10	-1.6	-1.3	-0.9	
			15	-4.2	-3.4	-2.4	

**AC ELECTRICAL CHARACTERISTICS** ( $C_L=50$  pF,  $R_L=200$  k $\Omega$ ,  $t_r=t_f=20$  ns)

Symbol	Parameter	V <sub>CC</sub> V	Guaranteed Limit			Unit
			-55°C	25°C	125°C	
f <sub>max</sub>	Maximum Clock Frequency (Figure 1)	5.0	3.5	3.5	1.75	MHz
		10	8	8	4.0	
		15	12	12	6.0	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Clock to Q1 (Figure 1)	5.0	360	360	720	ns
		10	160	160	320	
		15	130	130	260	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Q <sub>n</sub> to Q <sub>n+1</sub> (Figure 2)	5.0	330	330	660	ns
		10	80	80	160	
		15	60	60	120	
t <sub>PHL</sub>	Maximum Propagation Delay, Reset to Any Q (Figure 3)	5.0	280	280	560	ns
		10	120	120	240	
		15	100	100	200	
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Any Output (Figure 1)	5.0	200	200	400	ns
		10	100	100	200	
		15	80	80	160	
C <sub>IN</sub>	Maximum Input Capacitance	-		7.5		pF

**TIMING REQUIREMENTS** ( $C_L=50$  pF,  $R_L=200$  k $\Omega$ ,  $t_r=t_f=20$  ns)

Symbol	Parameter	V <sub>CC</sub> V	Guaranteed Limit			Unit
			-55°C	25°C	125°C	
t <sub>w</sub>	Minimum Pulse Width, Clock (Figure 1)	5.0	140	140	280	ns
		10	60	60	120	
		15	40	40	80	
t <sub>w</sub>	Minimum Pulse Width, Reset (Figure 3)	5.0	200	200	400	ns
		10	80	80	160	
		15	60	60	120	
t <sub>rem</sub>	Minimum Removal Time, Reset(Figure 3)	5.0	350	350	700	ns
		10	150	150	300	
		15	100	100	200	
t <sub>r</sub> , t <sub>f</sub>	Maximum Input Rise and Fall Times, Clock (Figure 1)	5.0 10 15	Unlimited			ns

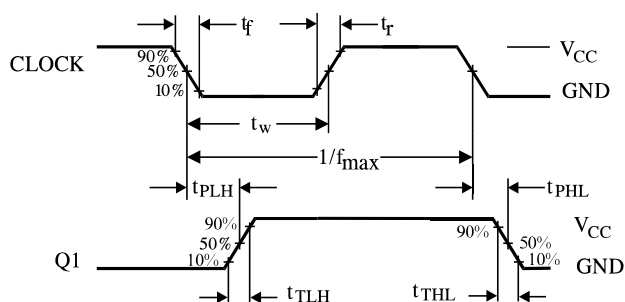


Figure 1. Switching Waveforms

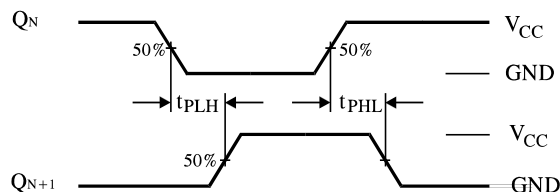


Figure 2. Switching Waveforms

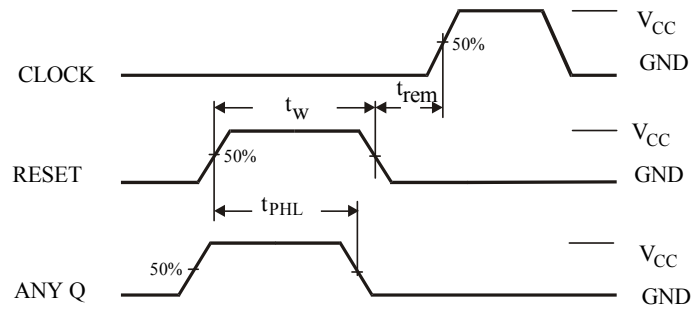
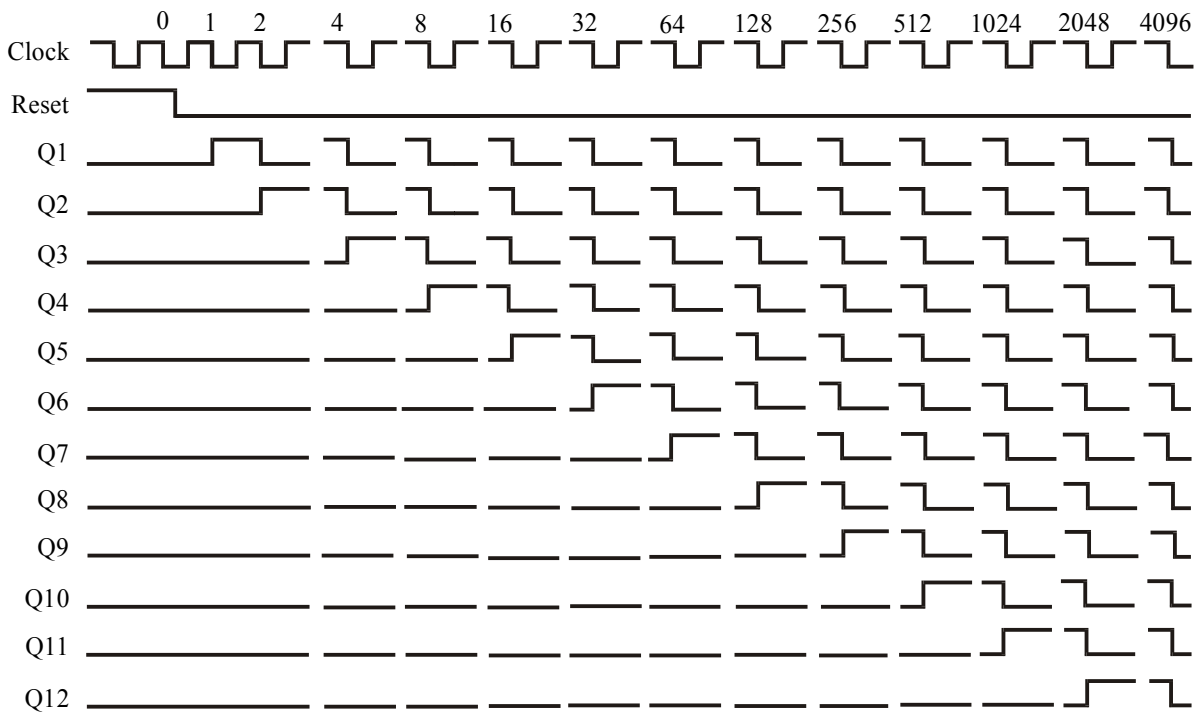
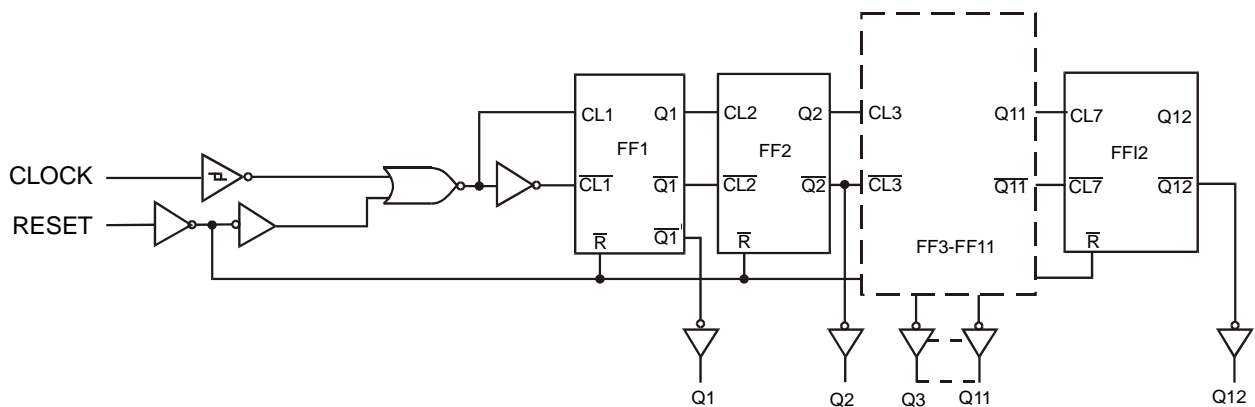


Figure 3. Switching Waveforms

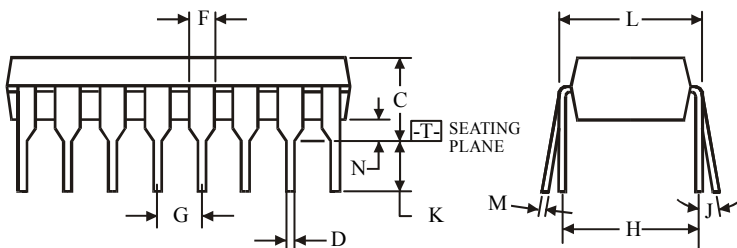
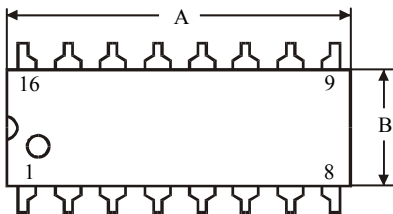
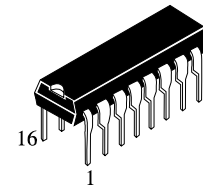
**TIMING DIAGRAM**



**EXPANDED LOGIC DIAGRAM**



**N SUFFIX PLASTIC  
(MS - 001BB)**



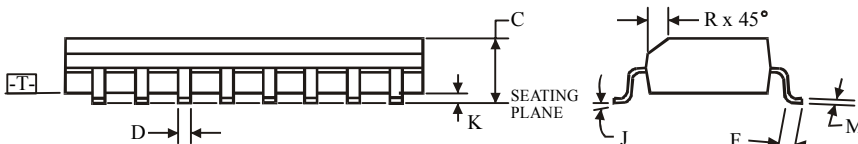
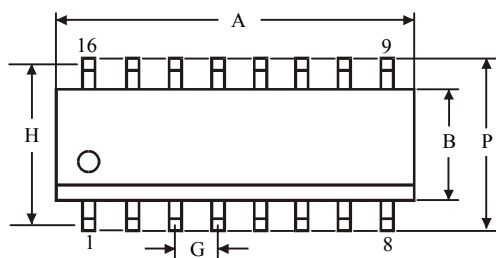
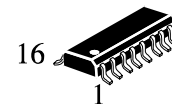
$\oplus 0.25 (0.010) \text{ (M) } | \text{ T}$

Symbol	Dimensions, mm	
	MIN	MAX
A	18.67	19.69
B	6.10	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.20	0.36
N	0.38	

**NOTES:**

- Dimensions "A", "B" do not include mold flash or protrusions. Maximum mold flash or protrusions 0.25 mm (0.010) per side.

**D SUFFIX SOIC  
(MS - 012AC)**



$\oplus 0.25 (0.010) \text{ (M) } | \text{ T } | \text{ C (M)}$

Symbol	Dimensions, mm	
	MIN	MAX
A	9.80	10.0
B	3.80	4.00
C	1.35	1.75
D	0.33	0.51
F	0.40	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.10	0.25
M	0.19	0.25
P	5.80	6.20
R	0.25	0.50

**NOTES:**

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A, for B - 0.25 mm (0.010) per side.